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# Intel - EPF10K200SFC484-2N Datasheet



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# Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

# **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

# Details

Product Status	Obsolete
Number of LABs/CLBs	1248
Number of Logic Elements/Cells	9984
Total RAM Bits	98304
Number of I/O	369
Number of Gates	513000
Voltage - Supply	2.375V ~ 2.625V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	484-BBGA
Supplier Device Package	484-FBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/intel/epf10k200sfc484-2n

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

Table J. FLEX TOKE FETTOTTIAILE										
Application	Resource	es Used		Performance		Units				
	LEs	EABs	-1 Speed Grade	-2 Speed Grade	-3 Speed Grade					
16-bit loadable counter	16	0	285	250	200	MHz				
16-bit accumulator	16	0	285	250	200	MHz				
16-to-1 multiplexer (1)	10	0	3.5	4.9	7.0	ns				
16-bit multiplier with 3-stage pipeline (2)	592	0	156	131	93	MHz				
$256 \times 16$ RAM read cycle speed (2)	0	1	196	154	118	MHz				
$256 \times 16$ RAM write cycle speed (2)	0	1	185	143	106	MHz				

# Table 5. FLEX 10KE Performance

#### Notes:

(1) This application uses combinatorial inputs and outputs.

(2) This application uses registered inputs and outputs.

Table 6 shows FLEX 10KE performance for more complex designs. These designs are available as Altera MegaCore $^{\circ}$  functions.

Table 6. FLEX 10KE Performance for Complex Designs									
Application	LEs Used		Performance						
		-1 Speed Grade	-2 Speed Grade	-3 Speed Grade					
8-bit, 16-tap parallel finite impulse response (FIR) filter	597	192	156	116	MSPS				
8-bit, 512-point fast Fourier	1,854	23.4	28.7	38.9	µs (1)				
transform (FFT) function		113	92	68	MHz				
a16450 universal asynchronous receiver/transmitter (UART)	342	36	28	20.5	MHz				

## Note:

(1) These values are for calculation time. Calculation time = number of clocks required /  $f_{max}$ . Number of clocks required = ceiling [log 2 (points)/2] × [points +14 + ceiling]

The EAB can also be used for bidirectional, dual-port memory applications where two ports read or write simultaneously. To implement this type of dual-port memory, two EABs are used to support two simultaneous read or writes.

Alternatively, one clock and clock enable can be used to control the input registers of the EAB, while a different clock and clock enable control the output registers (see Figure 2).



#### Notes:

- (1) All registers can be asynchronously cleared by EAB local interconnect signals, global signals, or the chip-wide reset.
- (2) EPF10K30E and EPF10K50E devices have 88 EAB local interconnect channels; EPF10K100E, EPF10K130E, and EPF10K200E devices have 104 EAB local interconnect channels.

For improved routing, the row interconnect consists of a combination of full-length and half-length channels. The full-length channels connect to all LABs in a row; the half-length channels connect to the LABs in half of the row. The EAB can be driven by the half-length channels in the left half of the row and by the full-length channels. The EAB drives out to the fulllength channels. In addition to providing a predictable, row-wide interconnect, this architecture provides increased routing resources. Two neighboring LABs can be connected using a half-row channel, thereby saving the other half of the channel for the other half of the row.

Table 7 summarizes the FastTrack Interconnect routing structure resources available in each FLEX 10KE device.

Table 7. FLEX 10KE FastTrack Interconnect Resources									
Device	Rows	Channels per Row	Columns	Channels per Column					
EPF10K30E	6	216	36	24					
EPF10K50E EPF10K50S	10	216	36	24					
EPF10K100E	12	312	52	24					
EPF10K130E	16	312	52	32					
EPF10K200E EPF10K200S	24	312	52	48					

In addition to general-purpose I/O pins, FLEX 10KE devices have six dedicated input pins that provide low-skew signal distribution across the device. These six inputs can be used for global clock, clear, preset, and peripheral output enable and clock enable control signals. These signals are available as control signals for all LABs and IOEs in the device. The dedicated inputs can also be used as general-purpose data inputs because they can feed the local interconnect of each LAB in the device.

Figure 14 shows the interconnection of adjacent LABs and EABs, with row, column, and local interconnects, as well as the associated cascade and carry chains. Each LAB is labeled according to its location: a letter represents the row and a number represents the column. For example, LAB B3 is in row B, column 3. Row-to-IOE Connections

When an IOE is used as an input signal, it can drive two separate row channels. The signal is accessible by all LEs within that row. When an IOE is used as an output, the signal is driven by a multiplexer that selects a signal from the row channels. Up to eight IOEs connect to each side of each row channel (see Figure 16).

# Figure 16. FLEX 10KE Row-to-IOE Connections The values for m and n are provided in Table 10.

IOE1 m Row FastTrack



Table 10 lists the	FLEX 10KE row-to	o-IOE interconnect resources.
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Table 10. FLEX 10KE Row-to-IOE Interconnect Resources									
Device	Row Channels per Pin (m)								
EPF10K30E	216	27							
EPF10K50E	216	27							
EPF10K50S									
EPF10K100E	312	39							
EPF10K130E	312	39							
EPF10K200E EPF10K200S	312	39							

 $\bigcirc$ 

# SameFrame Pin-Outs FLEX 10KE devices support the SameFrame pin-out feature for FineLine BGA packages. The SameFrame pin-out feature is the arrangement of balls on FineLine BGA packages such that the lower-ballcount packages form a subset of the higher-ball-count packages. SameFrame pin-outs provide the flexibility to migrate not only from device to device within the same package, but also from one package to another. A given printed circuit board (PCB) layout can support multiple device density/package combinations. For example, a single board layout can support a range of devices from an EPF10K30E device in a 256-pin FineLine BGA package.

The Altera software provides support to design PCBs with SameFrame pin-out devices. Devices can be defined for present and future use. The Altera software generates pin-outs describing how to lay out a board to take advantage of this migration (see Figure 18).





Printed Circuit Board Designed for 672-Pin FineLine BGA Package



 

 256-Pin FineLine BGA Package (Reduced I/O Count or Logic Requirements)
 672-Pin FineLine BGA Package (Increased I/O Count or Logic Requirements)

Table 13. ClockLock & ClockBoost Parameters for -2 Speed-Grade Devices										
Symbol	Parameter	Condition	Min	Тур	Max	Unit				
t <sub>R</sub>	Input rise time				5	ns				
t <sub>F</sub>	Input fall time				5	ns				
t <sub>INDUTY</sub>	Input duty cycle		40		60	%				
f <sub>CLK1</sub>	Input clock frequency (ClockBoost clock multiplication factor equals 1)		25		75	MHz				
f <sub>CLK2</sub>	Input clock frequency (ClockBoost clock multiplication factor equals 2)		16		37.5	MHz				
f <sub>CLKDEV</sub>	Input deviation from user specification in the MAX+PLUS II software (1)				25,000 (2)	PPM				
t <sub>INCLKSTB</sub>	Input clock stability (measured between adjacent clocks)				100	ps				
t <sub>LOCK</sub>	Time required for ClockLock or ClockBoost to acquire lock (3)				10	μs				
t <sub>JITTER</sub>	Jitter on ClockLock or ClockBoost-	$t_{INCLKSTB} < 100$			250	ps				
	generated clock (4)	$t_{INCLKSTB} < 50$			200 (4)	ps				
toutduty	Duty cycle for ClockLock or ClockBoost-generated clock		40	50	60	%				

#### Notes to tables:

- (1) To implement the ClockLock and ClockBoost circuitry with the MAX+PLUS II software, designers must specify the input frequency. The Altera software tunes the PLL in the ClockLock and ClockBoost circuitry to this frequency. The f<sub>CLKDEV</sub> parameter specifies how much the incoming clock can differ from the specified frequency during device operation. Simulation does not reflect this parameter.
- (2) Twenty-five thousand parts per million (PPM) equates to 2.5% of input clock period.
- (3) During device configuration, the ClockLock and ClockBoost circuitry is configured before the rest of the device. If the incoming clock is supplied during configuration, the ClockLock and ClockBoost circuitry locks during configuration because the t<sub>LOCK</sub> value is less than the time required for configuration.
- (4) The t<sub>ITTER</sub> specification is measured under long-term observation. The maximum value for t<sub>ITTER</sub> is 200 ps if t<sub>INCLKSTB</sub> is lower than 50 ps.

# I/O Configuration

This section discusses the peripheral component interconnect (PCI) pull-up clamping diode option, slew-rate control, open-drain output option, and MultiVolt I/O interface for FLEX 10KE devices. The PCI pull-up clamping diode, slew-rate control, and open-drain output options are controlled pin-by-pin via Altera software logic options. The MultiVolt I/O interface is controlled by connecting  $V_{CCIO}$  to a different voltage than  $V_{CCINT}$ . Its effect can be simulated in the Altera software via the **Global Project Device Options** dialog box (Assign menu).

# PCI Pull-Up Clamping Diode Option

FLEX 10KE devices have a pull-up clamping diode on every I/O, dedicated input, and dedicated clock pin. PCI clamping diodes clamp the signal to the  $V_{\rm CCIO}$  value and are required for 3.3-V PCI compliance. Clamping diodes can also be used to limit overshoot in other systems.

Clamping diodes are controlled on a pin-by-pin basis. When  $V_{CCIO}$  is 3.3 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V or 3.3-V signal, but not a 5.0-V signal. When  $V_{CCIO}$  is 2.5 V, a pin that has the clamping diode option turned on can be driven by a 2.5-V signal, but not a 3.3-V or 5.0-V signal. Additionally, a clamping diode can be activated for a subset of pins, which would allow a device to bridge between a 3.3-V PCI bus and a 5.0-V device.

# **Slew-Rate Control**

The output buffer in each IOE has an adjustable output slew rate that can be configured for low-noise or high-speed performance. A slower slew rate reduces system noise and adds a maximum delay of 4.3 ns. The fast slew rate should be used for speed-critical outputs in systems that are adequately protected against noise. Designers can specify the slew rate pin-by-pin or assign a default slew rate to all pins on a device-wide basis. The slow slew rate setting affects the falling edge of the output.

# **Open-Drain Output Option**

FLEX 10KE devices provide an optional open-drain output (electrically equivalent to open-collector output) for each I/O pin. This open-drain output enables the device to provide system-level control signals (e.g., interrupt and write enable signals) that can be asserted by any of several devices. It can also provide an additional wired-OR plane.

# MultiVolt I/O Interface

The FLEX 10KE device architecture supports the MultiVolt I/O interface feature, which allows FLEX 10KE devices in all packages to interface with systems of differing supply voltages. These devices have one set of  $V_{CC}$  pins for internal operation and input buffers (VCCINT), and another set for I/O output drivers (VCCIO).

Figure 20 shows the timing requirements for the JTAG signals.



Figure 20. FLEX 10KE JTAG Waveforms

# Table 18 shows the timing parameters and values for FLEX 10KE devices.

Table 18. FLEX 10KE JTAG Timing Parameters & Values									
Symbol	Parameter	Min	Мах	Unit					
t <sub>JCP</sub>	TCK clock period	100		ns					
t <sub>JCH</sub>	TCK clock high time	50		ns					
t <sub>JCL</sub>	TCK clock low time	50		ns					
t <sub>JPSU</sub>	JTAG port setup time	20		ns					
t <sub>JPH</sub>	JTAG port hold time	45		ns					
t <sub>JPCO</sub>	JTAG port clock to output		25	ns					
t <sub>JPZX</sub>	JTAG port high impedance to valid output		25	ns					
t <sub>JPXZ</sub>	JTAG port valid output to high impedance		25	ns					
t <sub>JSSU</sub>	Capture register setup time	20		ns					
t <sub>JSH</sub>	Capture register hold time	45		ns					
t <sub>JSCO</sub>	Update register clock to output		35	ns					
t <sub>JSZX</sub>	Update register high impedance to valid output		35	ns					
t <sub>JSXZ</sub>	Update register valid output to high impedance		35	ns					





#### Figure 23. Output Drive Characteristics of FLEX 10KE Devices Note (1)

#### Note:

(1) These are transient (AC) currents.

# **Timing Model**

The continuous, high-performance FastTrack Interconnect routing resources ensure predictable performance and accurate simulation and timing analysis. This predictable performance contrasts with that of FPGAs, which use a segmented connection scheme and therefore have unpredictable performance.

Device performance can be estimated by following the signal path from a source, through the interconnect, to the destination. For example, the registered performance between two LEs on the same row can be calculated by adding the following parameters:

- LE register clock-to-output delay (*t*<sub>CO</sub>)
- Interconnect delay (t<sub>SAMEROW</sub>)
- **LE** look-up table delay  $(t_{LUT})$
- **LE** register setup time  $(t_{SU})$

The routing delay depends on the placement of the source and destination LEs. A more complex registered path may involve multiple combinatorial LEs between the source and destination LEs.

Figure 25. FLEX 10KE Device LE Timing Model



Figures 29 and 30 show the asynchronous and synchronous timing waveforms, respectively, or the EAB macroparameters in Tables 26 and 27.

EAB Asynchronous Read WE \_ a0 a2 Address a1 a3 – t<sub>EABAA</sub>t<sub>EABRCCOMB</sub> Data-Out d0 d3 d1 d2 **EAB Asynchronous Write** WE  $t_{EABWP}$ ► t<sub>EABWDH</sub> t<sub>EABWDSU</sub> × a din0 din1 Data-In t<sub>EABWASU</sub> t<sub>EABWAH</sub> t<sub>EABWCCOMB</sub> Address a0 a1 a2  $t_{EABDD}$ Data-Out din0 din1 dout2

## Figure 29. EAB Asynchronous Timing Waveforms

Table 31. EPF10K30E Device LE Timing Microparameters (Part 2 of 2)       Note (1)								
Symbol	-1 Spee	d Grade	-2 Spee	d Grade	-3 Spee	ed Grade	Unit	
	Min	Max	Min	Max	Min	Max		
t <sub>CGENR</sub>		0.1		0.1		0.2	ns	
t <sub>CASC</sub>		0.6		0.8		1.0	ns	
t <sub>C</sub>		0.0		0.0		0.0	ns	
t <sub>CO</sub>		0.3		0.4		0.5	ns	
t <sub>COMB</sub>		0.4		0.4		0.6	ns	
t <sub>SU</sub>	0.4		0.6		0.6		ns	
t <sub>H</sub>	0.7		1.0		1.3		ns	
t <sub>PRE</sub>		0.8		0.9		1.2	ns	
t <sub>CLR</sub>		0.8		0.9		1.2	ns	
t <sub>CH</sub>	2.0		2.5		2.5		ns	
t <sub>CL</sub>	2.0		2.5		2.5		ns	

Table 32. EPF10K30E Device IOE Timing Microparameters       Note (1)								
Symbol	-1 Spee	ed Grade	-2 Spee	ed Grade	-3 Spee	ed Grade	Unit	
	Min	Max	Min	Max	Min	Мах		
t <sub>IOD</sub>		2.4		2.8		3.8	ns	
t <sub>IOC</sub>		0.3		0.4		0.5	ns	
t <sub>IOCO</sub>		1.0		1.1		1.6	ns	
t <sub>IOCOMB</sub>		0.0		0.0		0.0	ns	
t <sub>IOSU</sub>	1.2		1.4		1.9		ns	
t <sub>IOH</sub>	0.3		0.4		0.5		ns	
t <sub>IOCLR</sub>		1.0		1.1		1.6	ns	
t <sub>OD1</sub>		1.9		2.3		3.0	ns	
t <sub>OD2</sub>		1.4		1.8		2.5	ns	
t <sub>OD3</sub>		4.4		5.2		7.0	ns	
t <sub>XZ</sub>		2.7		3.1		4.3	ns	
t <sub>ZX1</sub>		2.7		3.1		4.3	ns	
t <sub>ZX2</sub>		2.2		2.6		3.8	ns	
t <sub>ZX3</sub>		5.2		6.0		8.3	ns	
t <sub>INREG</sub>		3.4		4.1		5.5	ns	
t <sub>IOFD</sub>		0.8		1.3		2.4	ns	
t <sub>INCOMB</sub>		0.8		1.3		2.4	ns	

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Table 38. EPF10K50E Device LE Timing Microparameters (Part 2 of 2)       Note (1)									
Symbol	-1 Speed Grade		-2 Speed Grade		-3 Speed Grade		Unit		
	Min	Max	Min	Max	Min	Max			
t <sub>H</sub>	0.9		1.0		1.4		ns		
t <sub>PRE</sub>		0.5		0.6		0.8	ns		
t <sub>CLR</sub>		0.5		0.6		0.8	ns		
t <sub>CH</sub>	2.0		2.5		3.0		ns		
t <sub>CL</sub>	2.0		2.5		3.0		ns		

Table 39. EPF10K50E Device IOE Timing Microparameters       Note (1)								
Symbol	-1 Spee	d Grade	-2 Spee	ed Grade	-3 Spee	ed Grade	Unit	
	Min	Max	Min	Max	Min	Max		
t <sub>IOD</sub>		2.2		2.4		3.3	ns	
t <sub>IOC</sub>		0.3		0.3		0.5	ns	
t <sub>IOCO</sub>		1.0		1.0		1.4	ns	
t <sub>IOCOMB</sub>		0.0		0.0		0.2	ns	
t <sub>IOSU</sub>	1.0		1.2		1.7		ns	
t <sub>IOH</sub>	0.3		0.3		0.5		ns	
t <sub>IOCLR</sub>		0.9		1.0		1.4	ns	
t <sub>OD1</sub>		0.8		0.9		1.2	ns	
t <sub>OD2</sub>		0.3		0.4		0.7	ns	
t <sub>OD3</sub>		3.0		3.5		3.5	ns	
t <sub>XZ</sub>		1.4		1.7		2.3	ns	
t <sub>ZX1</sub>		1.4		1.7		2.3	ns	
t <sub>ZX2</sub>		0.9		1.2		1.8	ns	
t <sub>ZX3</sub>		3.6		4.3		4.6	ns	
t <sub>INREG</sub>		4.9		5.8		7.8	ns	
t <sub>IOFD</sub>		2.8		3.3		4.5	ns	
t <sub>INCOMB</sub>		2.8		3.3		4.5	ns	

Table 58. EPF10K130E External Bidirectional Timing Parameters       Notes (1), (2)							
Symbol	-1 Spee	ed Grade	-2 Spee	d Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSUBIDIR</sub> (3)	2.2		2.4		3.2		ns
t <sub>INHBIDIR</sub> (3)	0.0		0.0		0.0		ns
t <sub>INSUBIDIR</sub> (4)	2.8		3.0		-		ns
t <sub>INHBIDIR</sub> (4)	0.0		0.0		-		ns
toutcobidir (3)	2.0	5.0	2.0	7.0	2.0	9.2	ns
t <sub>XZBIDIR</sub> (3)		5.6		8.1		10.8	ns
t <sub>ZXBIDIR</sub> (3)		5.6		8.1		10.8	ns
toutcobidir (4)	0.5	4.0	0.5	6.0	_	-	ns
t <sub>XZBIDIR</sub> (4)		4.6		7.1		-	ns
t <sub>ZXBIDIR</sub> (4)		4.6		7.1		-	ns

## Notes to tables:

(1) All timing parameters are described in Tables 24 through 30 in this data sheet.

(2) These parameters are specified by characterization.

(3) This parameter is measured without the use of the ClockLock or ClockBoost circuits.

(4) This parameter is measured with the use of the ClockLock or ClockBoost circuits.

# Tables 59 through 65 show EPF10K200E device internal and external timing parameters.

Table 59. EPF10K200E Device LE Timing Microparameters (Part 1 of 2)       Note (1)							
Symbol	-1 Spee	d Grade	d Grade -2 Spee		ed Grade -3 Speed		Unit
	Min	Max	Min	Max	Min	Max	
t <sub>LUT</sub>		0.7		0.8		1.2	ns
t <sub>CLUT</sub>		0.4		0.5		0.6	ns
t <sub>RLUT</sub>		0.6		0.7		0.9	ns
t <sub>PACKED</sub>		0.3		0.5		0.7	ns
t <sub>EN</sub>		0.4		0.5		0.6	ns
t <sub>CICO</sub>		0.2		0.2		0.3	ns
t <sub>CGEN</sub>		0.4		0.4		0.6	ns
t <sub>CGENR</sub>		0.2		0.2		0.3	ns
t <sub>CASC</sub>		0.7		0.8		1.2	ns
t <sub>C</sub>		0.5		0.6		0.8	ns
t <sub>CO</sub>		0.5		0.6		0.8	ns
t <sub>COMB</sub>		0.4		0.6		0.8	ns
t <sub>SU</sub>	0.4		0.6		0.7		ns

Symbol	-1 Spee	ed Grade	-2 Spee	-2 Speed Grade		ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>EABDATA1</sub>		1.7		2.4		3.2	ns
t <sub>EABDATA2</sub>		0.4		0.6		0.8	ns
t <sub>EABWE1</sub>		1.0		1.4		1.9	ns
t <sub>EABWE2</sub>		0.0		0.0		0.0	ns
t <sub>EABRE1</sub>		0.0		0.0		0.0	
t <sub>EABRE2</sub>		0.4		0.6		0.8	
t <sub>EABCLK</sub>		0.0		0.0		0.0	ns
t <sub>EABCO</sub>		0.8		1.1		1.5	ns
t <sub>EABBYPASS</sub>		0.0		0.0		0.0	ns
t <sub>EABSU</sub>	0.7		1.0		1.3		ns
t <sub>EABH</sub>	0.4		0.6		0.8		ns
t <sub>EABCLR</sub>	0.8		1.1		1.5		
t <sub>AA</sub>		2.0		2.8		3.8	ns
t <sub>WP</sub>	2.0		2.8		3.8		ns
t <sub>RP</sub>	1.0		1.4		1.9		
t <sub>WDSU</sub>	0.5		0.7		0.9		ns
t <sub>WDH</sub>	0.1		0.1		0.2		ns
t <sub>WASU</sub>	1.0		1.4		1.9		ns
t <sub>WAH</sub>	1.5		2.1		2.9		ns
t <sub>RASU</sub>	1.5		2.1		2.8		
t <sub>RAH</sub>	0.1		0.1		0.2		
t <sub>WO</sub>		2.1		2.9		4.0	ns
t <sub>DD</sub>		2.1		2.9		4.0	ns
t <sub>EABOUT</sub>		0.0		0.0		0.0	ns
t <sub>EABCH</sub>	1.5		2.0		2.5		ns
t <sub>EABCL</sub>	1.5		2.0		2.5		ns

Table 69. EPF10K50S Device EAB Internal Timing Macroparameters         Note (1)							
Symbol	-1 Spee	ed Grade	d Grade -2 Spee		d Grade -3 Speed		Unit
	Min	Max	Min	Мах	Min	Max	
t <sub>EABAA</sub>		3.7		5.2		7.0	ns
t <sub>EABRCCOMB</sub>	3.7		5.2		7.0		ns
t <sub>EABRCREG</sub>	3.5		4.9		6.6		ns
t <sub>EABWP</sub>	2.0		2.8		3.8		ns
t <sub>EABWCCOMB</sub>	4.5		6.3		8.6		ns
t <sub>EABWCREG</sub>	5.6		7.8		10.6		ns
t <sub>EABDD</sub>		3.8		5.3		7.2	ns
t <sub>EABDATACO</sub>		0.8		1.1		1.5	ns
t <sub>EABDATASU</sub>	1.1		1.6		2.1		ns
t <sub>EABDATAH</sub>	0.0		0.0		0.0		ns
t <sub>EABWESU</sub>	0.7		1.0		1.3		ns
t <sub>EABWEH</sub>	0.4		0.6		0.8		ns
t <sub>EABWDSU</sub>	1.2		1.7		2.2		ns
t <sub>EABWDH</sub>	0.0		0.0		0.0		ns
t <sub>EABWASU</sub>	1.6		2.3		3.0		ns
t <sub>EABWAH</sub>	0.9		1.2		1.8		ns
t <sub>EABWO</sub>		3.1		4.3		5.9	ns

Table 70. EPF10K50S Device Interconnect Timing Microparameters         Note (1)							
Symbol	-1 Spee	ed Grade	-2 Speed Grade		-3 Speed Grade		Unit
	Min	Max	Min	Max	Min	Мах	
t <sub>DIN2IOE</sub>		3.1		3.7		4.6	ns
t <sub>DIN2LE</sub>		1.7		2.1		2.7	ns
t <sub>DIN2DATA</sub>		2.7		3.1		5.1	ns
t <sub>DCLK2IOE</sub>		1.6		1.9		2.6	ns
t <sub>DCLK2LE</sub>		1.7		2.1		2.7	ns
t <sub>SAMELAB</sub>		0.1		0.1		0.2	ns
t <sub>SAMEROW</sub>		1.5		1.7		2.4	ns
t <sub>SAMECOLUMN</sub>		1.0		1.3		2.1	ns
t <sub>DIFFROW</sub>		2.5		3.0		4.5	ns
t <sub>TWOROWS</sub>		4.0		4.7		6.9	ns
t <sub>LEPERIPH</sub>		2.6		2.9		3.4	ns
t <sub>LABCARRY</sub>		0.1		0.2		0.2	ns
t <sub>LABCASC</sub>		0.8		1.0		1.3	ns

Table 71. EPF10K50S External Timing Parameters     Note (1)							
Symbol	-1 Spee	ed Grade	-2 Spee	-2 Speed Grade		d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>DRR</sub>		8.0		9.5		12.5	ns
t <sub>INSU</sub> (2)	2.4		2.9		3.9		ns
t <sub>INH</sub> (2)	0.0		0.0		0.0		ns
t <sub>OUTCO</sub> (2)	2.0	4.3	2.0	5.2	2.0	7.3	ns
t <sub>INSU</sub> (3)	2.4		2.9				ns
t <sub>INH</sub> (3)	0.0		0.0				ns
t <sub>оитсо</sub> (3)	0.5	3.3	0.5	4.1			ns
t <sub>PCISU</sub>	2.4		2.9		-		ns
t <sub>PCIH</sub>	0.0		0.0		-		ns
t <sub>PCICO</sub>	2.0	6.0	2.0	7.7	_	-	ns

 Table 72. EPF10K50S External Bidirectional Timing Parameters
 Note (1)

Symbol	-1 Spee	ed Grade	-2 Spee	d Grade	-3 Spee	d Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>INSUBIDIR</sub> (2)	2.7		3.2		4.3		ns
t <sub>INHBIDIR</sub> (2)	0.0		0.0		0.0		ns
t <sub>INHBIDIR</sub> (3)	0.0		0.0		-		ns
t <sub>INSUBIDIR</sub> (3)	3.7		4.2		-		ns
t <sub>OUTCOBIDIR</sub> (2)	2.0	4.5	2.0	5.2	2.0	7.3	ns
t <sub>XZBIDIR</sub> (2)		6.8		7.8		10.1	ns
t <sub>ZXBIDIR</sub> (2)		6.8		7.8		10.1	ns
t <sub>outcobidir</sub> (3)	0.5	3.5	0.5	4.2	-	-	
t <sub>XZBIDIR</sub> (3)		6.8		8.4		-	ns
t <sub>ZXBIDIR</sub> (3)		6.8		8.4		-	ns

#### Notes to tables:

(1) All timing parameters are described in Tables 24 through 30.

(2) This parameter is measured without use of the ClockLock or ClockBoost circuits.

(3) This parameter is measured with use of the ClockLock or ClockBoost circuits

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Table 73. EPF10K200S Device Internal & External Timing Parameters       Note (1)							
Symbol	-1 Spee	ed Grade	-2 Spee	-2 Speed Grade		ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>LUT</sub>		0.7		0.8		1.2	ns
t <sub>CLUT</sub>		0.4		0.5		0.6	ns
t <sub>RLUT</sub>		0.5		0.7		0.9	ns
t <sub>PACKED</sub>		0.4		0.5		0.7	ns
t <sub>EN</sub>		0.6		0.5		0.6	ns
t <sub>CICO</sub>		0.1		0.2		0.3	ns
t <sub>CGEN</sub>		0.3		0.4		0.6	ns
t <sub>CGENR</sub>		0.1		0.2		0.3	ns
t <sub>CASC</sub>		0.7		0.8		1.2	ns
t <sub>C</sub>		0.5		0.6		0.8	ns
t <sub>CO</sub>		0.5		0.6		0.8	ns
t <sub>COMB</sub>		0.3		0.6		0.8	ns
t <sub>SU</sub>	0.4		0.6		0.7		ns
t <sub>H</sub>	1.0		1.1		1.5		ns
t <sub>PRE</sub>		0.4		0.6		0.8	ns
t <sub>CLR</sub>		0.5		0.6		0.8	ns
t <sub>CH</sub>	2.0		2.5		3.0		ns
t <sub>CL</sub>	2.0		2.5		3.0		ns

 Table 74. EPF10K200S Device IOE Timing Microparameters (Part 1 of 2)
 Note (1)

Symbol	-1 Spee	ed Grade	-2 Spee	ed Grade	-3 Spee	ed Grade	Unit
	Min	Max	Min	Max	Min	Max	
t <sub>IOD</sub>		1.8		1.9		2.6	ns
t <sub>IOC</sub>		0.3		0.3		0.5	ns
t <sub>IOCO</sub>		1.7		1.9		2.6	ns
t <sub>IOCOMB</sub>		0.5		0.6		0.8	ns
t <sub>IOSU</sub>	0.8		0.9		1.2		ns
t <sub>IOH</sub>	0.4		0.8		1.1		ns
t <sub>IOCLR</sub>		0.2		0.2		0.3	ns
t <sub>OD1</sub>		1.3		0.7		0.9	ns
t <sub>OD2</sub>		0.8		0.2		0.4	ns
t <sub>OD3</sub>		2.9		3.0		3.9	ns
t <sub>XZ</sub>		5.0		5.3		7.1	ns
t <sub>ZX1</sub>		5.0		5.3		7.1	ns

Additionally, the Altera software offers several features that help plan for future device migration by preventing the use of conflicting I/O pins.

Table 81. I/O Counts for FLEX 10KA & FLEX 10KE Devices						
FLEX 10	KA	FLEX 10	KE			
Device	I/O Count	Device	I/O Count			
EPF10K30AF256	191	EPF10K30EF256	176			
EPF10K30AF484	246	EPF10K30EF484	220			
EPF10K50VB356	274	EPF10K50SB356	220			
EPF10K50VF484	291	EPF10K50EF484	254			
EPF10K50VF484	291	EPF10K50SF484	254			
EPF10K100AF484	369	EPF10K100EF484	338			

**Configuration Schemes** 

The configuration data for a FLEX 10KE device can be loaded with one of five configuration schemes (see Table 82), chosen on the basis of the target application. An EPC1, EPC2, or EPC16 configuration device, intelligent controller, or the JTAG port can be used to control the configuration of a FLEX 10KE device, allowing automatic configuration on system power-up.

Multiple FLEX 10KE devices can be configured in any of the five configuration schemes by connecting the configuration enable (nCE) and configuration enable output (nCEO) pins on each device. Additional FLEX 10K, FLEX 10KA, FLEX 10KE, and FLEX 6000 devices can be configured in the same serial chain.

Table 82. Data Sources for FLEX 10KE Configuration					
Configuration Scheme	Data Source				
Configuration device	EPC1, EPC2, or EPC16 configuration device				
Passive serial (PS)	BitBlaster, ByteBlasterMV, or MasterBlaster download cables, or serial data source				
Passive parallel asynchronous (PPA)	Parallel data source				
Passive parallel synchronous (PPS)	Parallel data source				
JTAG	BitBlaster or ByteBlasterMV download cables, or microprocessor with a Jam STAPL file or JBC file				



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